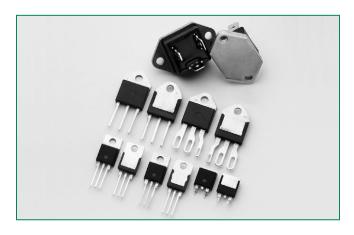


RoHS

Qxx25xx & Qxx25xHx Series





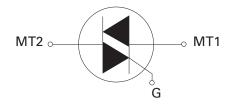
Agency Approval

Agency	Agency File Number
. 9 U	TO-220L, TO-218K, TO-218J & Fastpak Packages: E71639

Main Features

Symbol	Value	Unit
I _{T(RMS)}	25	А
V _{DRM} /V _{RRM}	1000	V
I _{GT}	50 to 80	mA

Schematic Symbol



Description

25 Amp bi-directional solid state switch series is designed for AC switching and phase control applications such as motor speed and temperature modulation controls, lighting controls, and static switching relays.

Standard type devices normally operate in Quadrants I & III triggered from AC line.

Alternistor type devices only operate in quadrants I, II, & III and are used in circuits requiring high dv/dt capability.

Features & Benefits

- RoHS compliant
- Glass passivated junctions
- Voltage capability up to 1000 V
- Surge capability up to 250 A

Applications

Excellent for AC switching and phase control applications such as heating, lighting, and motor speed controls.

Typical applications are AC solid-state switches, industrial power tools, exercise equipment, white goods and commercial appliances.

Alternistor Triacs (no snubber required) are used in applications with extremely inductive loads requiring highest commutation performance.

Internally constructed isolated packages are offered for ease of heat sinking with highest isolation voltage.

Teccor® brand Thyristors 25 Amp Standard & Alternistor (High Commutation) Triacs



Absolute Maximum Ratings – Standard Triac

Symbol	Parameter	Te	Value	Unit	
I _{T(RMS)}	RMS on-state current	Qxx25R5 Qxx25N5	T _c = 85°C	25	А
T(TINO)		Qxx25P5	T _C = 57°C		
		Qxx25R5	single half cycle; $f = 50Hz$; T_J (initial) = 25°C	167	
1	Dock pan repetitive ourse oursent	Qxx25N5	single half cycle; $f = 60Hz$; T_J (initial) = 25°C	200	А
I _{TSM}	Peak non-repetitive surge current	Qxx25P5	single half cycle; $f = 50Hz$; T_J (initial) = 25°C	220	
			single half cycle; $f = 60Hz$; T_J (initial) = 25°C	250	
l²t	I ² t Value for fusing	Qxx25R5 Qxx25N5	t _n = 8.3ms	166	A ² s
	_	Qxx25P5	٢	260	
di/dt	Critical rate-of-rise of on-state current	f =	60Hz; T _J =125°C	100	A/µs
I _{GTM}	Peak gate current		T _J = 125°C	2	А
P _{G(AV)}	Average gate power dissipation		0.5	W	
T _{stg}	Storage temperature range		-40 to 125	°C	
T,	Operating junction temperature range		Qxx25R5 Qxx25N5	-40 to 125	°C
			Qxx25P5	-25 to 125	

Absolute Maximum Ratings – Alternistor Triac

Symbol	Parameter	Te	Value	Unit	
	RMS on-state current	Qxx25LH5 Qxx25L6	T _C = 65°C		
1		Qxx25K6 Qxx25J6	T _c = 85°C	25	A
^L T(RMS)		Qxx25RH5 Qxx25NH5 Qxx25R6 Qxx25NH6	T _c = 95°C		
1	Pook non ronatitivo gurgo gurrant	single half cycle; f = 50Hz; T _J (initial) = 25°C		208	А А
I _{TSM}	Peak non-repetitive surge current	single half cycle; $f = 60Hz$; T_J (initial) = 25°C		250	
l²t	I²t Value for fusing	t _p = 8.3ms		260	A ² s
di/dt	Critical rate-of-rise of on-state current	f = 60Hz; T _J =125°C		100	A/µs
I _{GTM}	Peak gate current	T _J = 125°C		2	А
P _{G(AV)}	Average gate power dissipation	T _J = 125°C		0.5	W
T _{stg}	Storage temperature range			-40 to 125	°C
T	Operating junction temperature range			-40 to 125	°C

Note: xx = voltage



Electrical Characteristics ($T_J = 25$ °C, unless otherwise specified) — Standard Triac

	Test Conditions Quad			Valu	ne		
Symbol			Quadrant		Qxx25P5	Unit	
		1 – 11 – 111	MAX.	50)	mA	
I _{GT}	V 10V/ B 60 O	IV	TYP.	12	0	MA	
	$V_D = 12V; R_L = 60 \Omega$	1 – 11 – 111	MAX.	1.3	3		
$V_{\rm GT}$		IV	TYP.	2.5		V	
V _{GD}	$V_D = V_{DRM}$; $R_L = 3.3 \text{ k}\Omega$; $T_J = 125$ °C ALL		MIN.	0.2		V	
I _H	$I_{T} = 400 \text{mA} \text{ (initial)}$		MAX.	100	50	mA	
		400V		275	_	V/µs	
du /d+	$V_D = V_{DRM}$; Gate Open; $T_J = 125$ °C	600V	MIN.	225	475		
dv/dt		800V		200	400		
	$V_D = V_{DRM}$; Gate Open; $T_J = 100$ °C	1000V	1000V		_		
(dv/dt)c	$(di/dt)c = 13.3 \text{ A/ms}; T_J = 125^{\circ}\text{C}$		MIN.	5		V/µs	
t _{gt}	$I_{G} = 2 \times I_{GT}$ PW = 15µs; $I_{T} = 35.4$ A		TYP.	4	3	μs	

Electrical Characteristics ($T_J = 25$ °C, unless otherwise specified) — Alternistor Triac

				Val	Value		
Symbol	Test Conditions	Quadrant		Qxx25RH5 Qxx25LH5 Qxx25NH5	Oxx25R6 Oxx25L6 Oxx25NH6 Oxx25K6 Oxx25J6	Unit	
I _{GT}	V - 12V: B - 60 O	1 – 11 – 111	MAX.	50	80	mA	
V _{GT}	$V_D = 12V; R_L = 60 \Omega$	1 – 11 – 111	MAX.	1.3		V	
V _{GD}	$V_{D} = V_{DRM}$; $R_{L} = 3.3 \text{ k}\Omega$; $T_{J} = 125^{\circ}\text{C}$ $I - II - III$		MIN.	0.2		V	
I _H	$I_{T} = 400 \text{mA} \text{ (initial)}$		MAX.	50	100	mA	
		400V		575	600		
-1/-14	$V_D = V_{DRM}$; Gate Open; $T_J = 125^{\circ}C$	600V	NAINI	500	600	\// ₁	
dv/dt		800V	MIN.	400	475	- V/μs	
	$V_D = V_{DRM}$; Gate Open; $T_J = 100$ °C	1000V		_	400		
(dv/dt)c	(di/dt)c = 13.3 A/ms; T _J = 125°C		MIN.	20	30	V/µs	
t _{gt}	$I_{G} = 2 \times I_{GT}$ PW = 15µs; $I_{T} = 35.4 \text{ A}$		TYP.	3	5	μs	

Static Characteristics

					Val	ue	
Symbol					Oxx25R5 Oxx25N5 Oxx25xH5 Oxx25x6 Oxx25NH6	Qxx25P5	Unit
V _{TM}	$I_{T} = 35.4A; t_{p} = 380 \mu s$			MAX.	1.8	1.4	V
		T 25°C	600 – 800V		10	100	
		$T_{J} = 25^{\circ}C$	1000V		20	_	
I_{DRM}/I_{RRM}	V_{DRM}/V_{RRM}	T _J = 100°C	600 – 800V	MAX.	500	_	μΑ
			1000V		1000	_	
		T _J = 125°C	600 – 800V		2000	5000	

Note: xx = voltage, x = package



Thermal Resistances

Symbol	Parameter	Value	Unit	
		Qxx25R5 / Qxx25N5 Qxx25R6 / Qxx25NH6 Qxx25RH5 / Qxx25NH5	0.89	
$R_{\theta(J-C)}$	Junction to case (AC)	Qxx25P5	1.6	°C/W
0,0 0,		Qxx25L6 / Qxx25LH5	2.0	
		Qxx25K6 / Qxx25J6	1.32	
R _{e(J-A)}	Junction to ambient	Qxx25Ry	45	20044
		Qxx25L6 / Qxx25LH5	50	°C/W

Note: xx = voltage, y = sensitivity

Figure 1: Normalized DC Gate Trigger Current vs. Junction Temperature

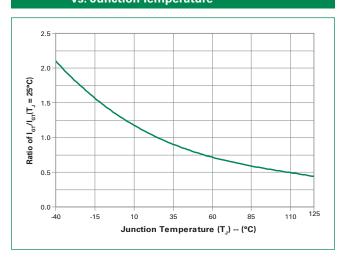


Figure 2: Normalized DC Gate Trigger Voltage vs. Junction Temperature

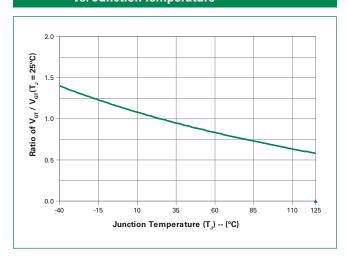


Figure 3: Normalized DC Holding Current vs. Junction Temperature

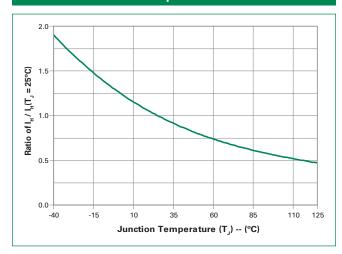


Figure 4: On-State Current vs. On-State Voltage (Typical)

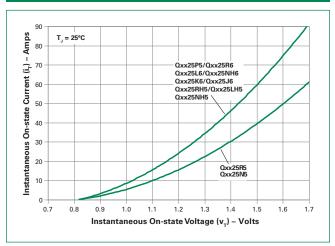




Figure 5: Power Dissipation (Typical) vs. RMS On-State Current

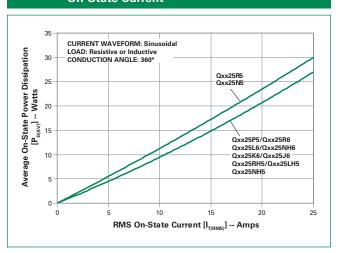


Figure 6: Maximum Allowable Case Temperature vs. RMS On-State Current

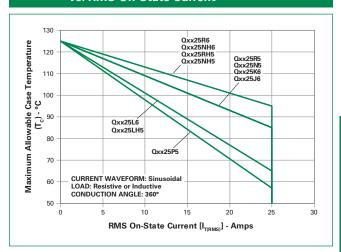


Figure 7: Maximum Allowable Ambient Temperature vs. RMS On-State Current (TO-220 packages only)

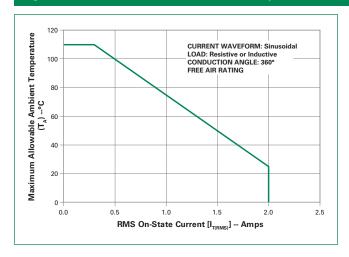
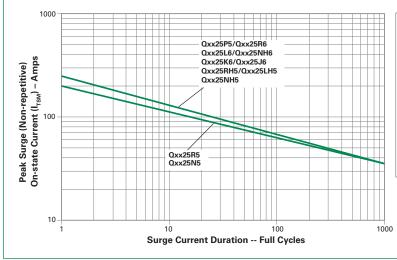


Figure 8: Surge Peak On-State Current vs. Number of Cycles



SUPPLY FREQUENCY: 60 Hz Sinusoidal

LOAD: Resistive

RMS On-State Current: [I $_{\text{T(RMS)}}$]: Maximum Rated Value at Specified Case Temperature

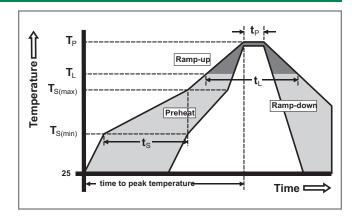
Notes

- 1. Gate control may be lost during and immediately following surge current interval.
- Overload may not be repeated until junction temperature has returned to steady-state rated value.



Soldering Parameters

Reflow Co	ndition	Pb – Free assembly
	-Temperature Min (T _{s(min)})	150°C
Pre Heat	-Temperature Max (T _{s(max)})	200°C
	-Time (min to max) (t _s)	60 – 180 secs
Average ra	amp up rate (LiquidusTemp) k	5°C/second max
T _{S(max)} to T _L - Ramp-up Rate		5°C/second max
Reflow	-Temperature (T _L) (Liquidus)	217°C
Reliow	-Temperature (t _L)	60 – 150 seconds
PeakTemp	erature (T _P)	260 ^{+0/-5} °C
Time within 5°C of actual peak Temperature (t _p)		20 - 40 seconds
Ramp-down Rate		5°C/second max
Time 25°C to peak Temperature (T _P)		8 minutes Max.
Do not exc	ceed	280°C



Physical Specifications

Terminal Finish	100% Matte Tin-plated
Body Material	UL recognized epoxy meeting flammability classification 94V-0
Lead Material	Copper Alloy

Design Considerations

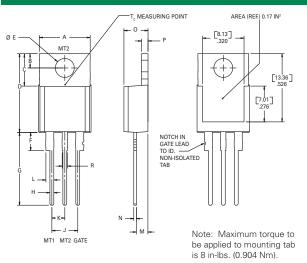
Careful selection of the correct device for the application's operating parameters and environment will go a long way toward extending the operating life of the Thyristor. Good design practice should limit the maximum continuous current through the main terminals to 75% of the device rating. Other ways to ensure long life for a power discrete semiconductor are proper heat sinking and selection of voltage ratings for worst case conditions. Overheating, overvoltage (including dv/dt), and surge currents are the main killers of semiconductors. Correct mounting, soldering, and forming of the leads also help protect against component damage.

Environmental Specifications

Test	Specifications and Conditions
High Temperature Voltage Blocking	MIL-STD-750: Method 1040, Condition A Rated V _{BRM} , 125°C, 1008 hours
Temperature Cycling	MIL-STD-750: Method 1051 -40°C to 125°C, 15-minute dwell, 100 cycles
Biased Temp & Humidity	EIA/JEDEC: JESD22-A101 320VDC, 85°C, 85%RH, 1008 hours
High Temp. Storage	MIL-STD-750: Method 1031 150°C, 1008 hours
Low-Temp Storage	-40°C, 1008 hours
Thermal Shock	MIL-STD-750: Method 1056 0°C to 100°C, 5-minute dwell, 10-second transfer, 10 cycles
Autoclave (Pressure Cooker Test)	EIA/JEDEC: JESD22-A102 121°C, 100%RH, 2atm, 168 hours
Resistance to Solder Heat	MIL-STD-750: Method 2031 260°C, 10 seconds
Solderability	ANSI/J-STD-002, Category 3, Test A
Lead Bend	MIL-STD-750: Method 2036, Condition E

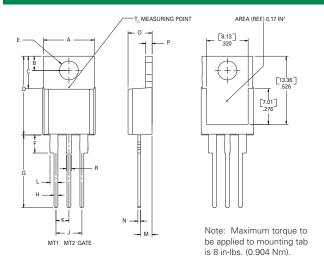


Dimensions — TO-220AB (R Package) — Non-isolated Mounting Tab



Dimension	Inc	hes	Millin	neters
Difficusion	Min	Max	Min	Max
А	0.380	0.420	9.65	10.67
В	0.105	0.115	2.67	2.92
С	0.230	0.250	5.84	6.35
D	0.590	0.620	14.99	15.75
Е	0.142	0.147	3.61	3.73
F	0.110	0.130	2.79	3.30
G	0.540	0.575	13.72	14.61
Н	0.025	0.035	0.64	0.89
J	0.195	0.205	4.95	5.21
K	0.095	0.105	2.41	2.67
L	0.060	0.075	1.52	1.91
М	0.085	0.095	2.16	2.41
N	0.018	0.024	0.46	0.61
0	0.178	0.188	4.52	4.78
Р	0.045	0.060	1.14	1.52
R	0.038	0.048	0.97	1.22

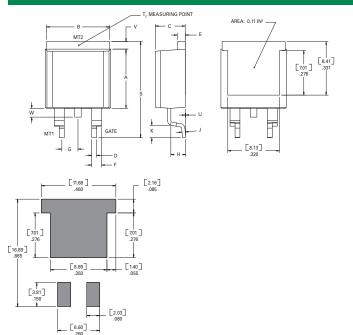
Dimensions — TO-220AB (L Package) — Isolated Mounting Tab



Dimension	Inc	hes	Millimeters		
Difficusion	Min	Max	Min	Max	
А	0.380	0.420	9.65	10.67	
В	0.105	0.115	2.66	2.92	
С	0.230	0.250	5.85	6.35	
D	0.590	0.620	14.98	15.75	
Е	0.142	0.147	3.61	3.73	
F	0.110	0.130	2.80	3.30	
G	0.540	0.575	13.71	14.60	
Н	0.025	0.035	0.63	0.89	
J	0.195	0.205	4.95	5.21	
K	0.095	0.105	2.41	2.67	
L	0.060	0.075	1.52	1.91	
М	0.085	0.095	1.78	2.16	
N	0.018	0.024	0.45	0.61	
0	0.178	0.188	4.52	4.78	
Р	0.045	0.060	1.14	1.53	
R	0.038	0.048	0.97	1.22	

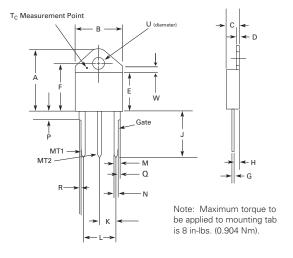


Dimensions — TO-263 (N Package) — D²Pak Surface Mount



Dimension	Incl	nes	Millimeters		
Difficusion	Min	Max	Min	Max	
А	0.360	0.370	9.14	9.40	
В	0.380	0.420	9.65	10.67	
С	0.178	0.188	4.52	4.78	
D	0.025	0.035	0.64	0.89	
Е	0.045	0.060	1.14	1.52	
F	0.060	0.075	1.52	1.91	
G	0.095	0.105	2.41	2.67	
Н	0.092	0.102	2.34	2.59	
J	0.018	0.024	0.46	0.61	
K	0.090	0.110	2.29	2.79	
S	0.590	0.625	14.99	15.88	
V	0.035	0.045	0.89	1.14	
U	0.002	0.010	0.05	0.25	
W	0.040	0.070	1.02	1.78	

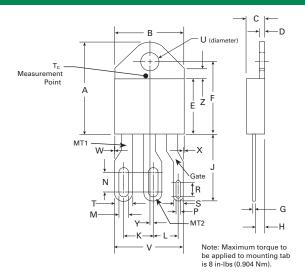
Dimensions — TO-218AC (K Package) — Isolated Mounting Tab



Dimension	Inc	hes	Millimeters		
Difficusion	Min	Max	Min	Max	
А	0.810	0.835	20.57	21.21	
В	0.610	0.630	15.49	16.00	
С	0.178	0.188	4.52	4.78	
D	0.055	0.070	1.40	1.78	
Е	0.487	0.497	12.37	12.62	
F	0.635	0.655	16.13	16.64	
G	0.022	0.029	0.56	0.74	
Н	0.075	0.095	1.91	2.41	
J	0.575	0.625	14.61	15.88	
K	0.211	0.219	5.36	5.56	
L	0.422	0.437	10.72	11.10	
М	0.058	0.068	1.47	1.73	
N	0.045	0.055	1.14	1.40	
Р	0.095	0.115	2.41	2.92	
Q	0.008	0.016	0.20	0.41	
R	0.008	0.016	0.20	0.41	
U	0.164	0.165	4.10	4.20	
W	0.085	0.095	2.17	2.42	

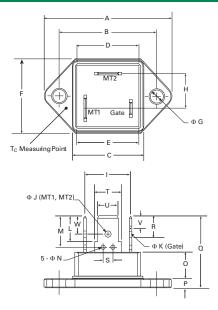


Dimensions — TO-218X (J Package) — Isolated Mounting Tab



Dimension	Inc	hes	Millimeters		
Difficusion	Min	Max	Min	Max	
А	0.810	0.835	20.57	21.21	
В	0.610	0.630	15.49	16.00	
С	0.178	0.188	4.52	4.78	
D	0.055	0.070	1.40	1.78	
Е	0.487	0.497	12.37	12.62	
F	0.635	0.655	16.13	16.64	
G	0.022	0.029	0.56	0.74	
Н	0.075	0.095	1.91	2.41	
J	0.575	0.625	14.61	15.88	
K	0.256	0.264	6.50	6.71	
L	0.220	0.228	5.58	5.79	
M	0.080	0.088	2.03	2.24	
N	0.169	0.177	4.29	4.49	
Р	0.034	0.042	0.86	1.07	
R	0.113	0.121	2.87	3.07	
S	0.086	0.096	2.18	2.44	
Т	0.156	0.166	3.96	4.22	
U	0.164	0.165	0.410	0.420	
V	0.603	0.618	15.31	15.70	
W	0.000	0.005	0.00	0.13	
X	0.003	0.012	0.07	0.30	
Υ	0.028	0.032	0.71	0.81	
Z	0.085	0.095	2.17	2.42	

Dimensions — TO-3 (P Package) Fastpak — Isolated Mounting Tab



Thickness off all three copper-alloy terminals is .032" (0.81 mm).

Dimension	Inc	nes	Millimeters		
Dimension	Min	Max	Min	Max	
А	1.531	1.543	38.90	39.20	
В	1.177	1.185	29.90	30.10	
С	0.843	0.850	21.40	21.60	
D	0.780	0.795	19.80	20.20	
Е	0.783	0.791	19.90	20.10	
F	0.874	0.906	22.20	23.00	
G	0.161	0.169	4.10	4.30	
Н	0.386	0.465	9.80	11.80	
I	0.508	0.587	12.90	14.90	
J	0.079	0.087	2.00	2.20	
K	0.047	0.055	1.20	1.40	
L	0.307	0.319	7.80	8.10	
М	0.372	0.396	9.45	10.05	
N	0.043	0.059	1.10	1.50	
0	0.315	0.331	8.00	8.40	
Р	0.098	0.106	2.50	2.70	
Q	0.846	0.886	21.50	22.50	
R	0.244	0.256	6.20	6.50	
S	0.106	0.130	2.70	3.30	
T (MT1)	0.321	0.329	8.15	8.35	
T (MT2)	0.321	0.329	8.15	8.35	
T (Gate)	0.220	0.228	5.60	5.80	
U (MT1)	0.246	0.254	6.25	6.45	
U (MT2)	0.246	0.254	6.25	6.45	
U (Gate)	0.183	0.191	4.65	4.85	
V	0.120	0.130	3.05	3.30	
W	0.175	0.185	4.45	4.70	
Maximum torque to be applied to mounting tab is 8 in-lbs (0.904Nm).					

Teccor® brand Thyristors 25 Amp Standard & Alternistor (High Commutation) Triacs



Product Selector

Part Number	Voltage			Gate Sensitivity Quadrants		Package	
	400V	600V	800V	1000V	1 - 11 - 111	IV	rackage
Qxx25R5	X	X	X	X	50 mA	120 mA (TYP)	TO-220R
Qxx25N5	X	X	X	X	50 mA	120 mA (TYP)	TO-263 D²-Pak
Qxx25P5		X	X		50 mA	120 mA (TYP)	Fastpak
Qxx25RH5	X	X	X		50 mA		TO-220R
Qxx25LH5	X	X	X		50 mA		TO-220L
Qxx25NH5	X	X	X		50 mA		TO-263 D²-Pak
Qxx25R6	X	X	X	X	80 mA		TO-220R
Qxx25L6	X	X	X	X	80 mA		TO-220L
Qxx25NH6	X	X	X	X	80 mA		TO-263 D ² -Pak
Qxx25J6	X	X	X		80 mA		TO-218X
Qxx25K6	X	X	X	X	80 mA		TO-218AC

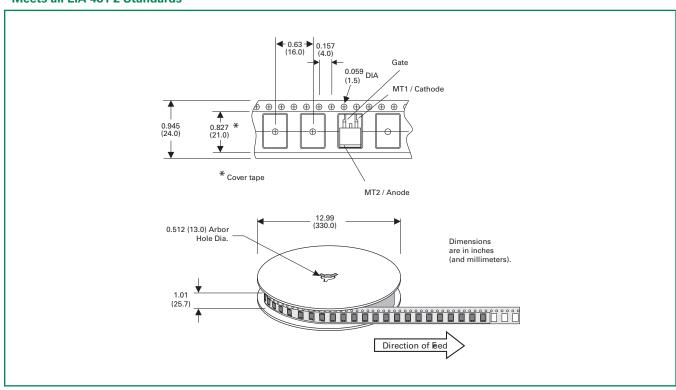
Packing Options

Part Number	Marking	Weight	Packing Mode	Base Quantity
Qxx25R5	Qxx25R5	2.20g	Bulk	500
Qxx25R5TP	Qxx25R5	2.20g	Tube	500 (50 per tube)
Qxx25N5TP	Qxx25N5	1.60g	Tube	500 (50 per tube)
Qxx25N5RP	Qxx25N5	1.60g	Embossed Carrier	500
Qxx25RH5	Qxx25RH5	2.20g	Bulk	500
Qxx25RH5TP	Qxx25RH5	2.20g	Tube	500 (50 per tube)
Qxx25LH5	Qxx25LH5	2.20g	Bulk	500
Qxx25LH5TP	Qxx25LH5	2.20g	Tube	500 (50 per tube)
Qxx25NH5TP	Qxx25NH5	1.60g	Tube	500 (50 per tube)
Qxx25NH5RP	Qxx25NH5	1.60g	Embossed Carrier	500
Qxx25P5	Qxx25P5	21.4g	Bulk	200
Qxx25R6	Qxx25R6	2.20g	Bulk	500
Qxx25R6TP	Qxx25R6	2.20g	Tube	500 (50 per tube)
Qxx25L6	Qxx25L6	2.20g	Bulk	500
Qxx25L6TP	Qxx25L6	2.20g	Tube	500 (50 per tube)
Qxx25NH6TP	Qxx25NH6	1.60g	Tube	500 (50 per tube)
Qxx25NH6RP	Qxx25NH6	1.60g	Embossed Carrier	500
Qxx25J6TP	Qxx25J6	5.23g	Tube	250 (25 per tube)
Qxx25K6TP	Qxx25K6	4.40g	Tube	250 (25 per tube)

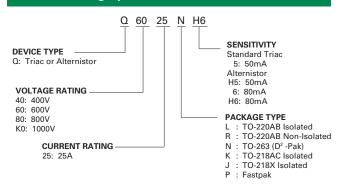


TO-263 Embossed Carrier Reel Pack (RP) Specifications

Meets all EIA-481-2 Standards



Part Numbering System



Part Marking System

